## NSN 5962-01-520-8980

Memory Microcircuit - Page 1 of 1



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| Maximum Dawar Dissinction Dating                   |
|--|
| Maximum Power Dissipation Rating:                  |
| 1.0 watts  |
| Operating Tempurature Range:                       |
| -55.0/+125.0 degrees celsius                       |
| Storage Tempurature Range:                         |
| -65.0/+150.0 degrees celsius                       |
| End Application:                                   |
| Eurofighter 2000                                   |
| Features Provided:                                 |
| Low power  |
| Inclosure Material:                                |
| Ceramic  |
| Inclosure Configuration:                           |
| Flat pack  |
| Output Logic Form:                                 |
| Complementary-metal oxide-semiconductor logic      |
| Terminal Surface Treatment:                        |
| Solder   |
| Voltage Rating And Type Per Characteristic:        |
| -0.5 volts power source and 7.0 volts power source |
| Time Rating Per Chacteristic:                      |
| 55.00 nanoseconds access                           |
| Memory Device Type:                                |
| Ram  |
| Memory Capacity:                                   |
| 128k by 8  |
| Terminal Type And Quantity:                        |
| 32 printed circuit                                 |
| Shelf Life:  |
| N/a  |
| Unit Of Measure:                                   |
|  |
| Demilitarization:                                  |
| Yes - demil/mli                                    |
| Fiig:  |
| A458a0   |
|  |